TOSHIBA Transistor Silicon NPN / PNP Epitaxial Type (PCT Process)

TPCP8902

Portable Equipment Applications Switching Applications

Small footprint due to small and thin package

• High DC current gain : PNP $h_{FE} = 200 \text{ to } 500 \text{ (I}_{C} = -0.2 \text{ A)}$

: NPN $h_{FE} = 200 \text{ to } 500 \text{ (IC} = 0.2 \text{ A)}$

• Low collector-emitter saturation : PNP $V_{CE (sat)} = -0.20 V (max)$

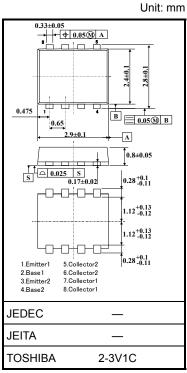
: NPN $V_{CE (sat)} = 0.14 \text{ V (max)}$

• High-speed switching : PNP $t_f = 40 \text{ ns (typ.)}$

: NPN $t_f = 45 \text{ ns (typ.)}$

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Cumbal | Rating | | Unit | |
|---------------------------------------|---------------------------------------|-------------------------|------------|-------|------|--|
| Character | Symbol | PNP | NPN | Offic | | |
| Collector-base voltage | | V_{CBO} | -30 | 60 | ٧ | |
| Collector-emitter voltage | | V _{CEX} | -30 | 50 | ٧ | |
| | | V_{CEO} | -30 | 30 | | |
| Emitter-base voltage | | V _{EBO} | -7 | 7 | > | |
| Collector current | DC (Note 1) | Ic | -2.0 | 2.0 | Α | |
| | Pulse (Note 1) | ICP | -8.0 | 8.0 | Α | |
| Base current | Base current | | | 0.5 | Α | |
| Collector power dissipation (t = 10s) | Single-device operation | | 1.67 | | W | |
| | Single-device value at dual operation | P _C (Note 2) | 0.9 | | | |
| Collector power dissipation (DC) | Single-device operation | | 0.89 | | | |
| | Single-device value at dual operation | P _C (Note 2) | 0.52 | | W | |
| Junction temperature | | Tj | 150 | | °C | |
| Storage temperature range | | T _{stg} | –55 to 150 | | °C | |



Weight: 0.017 g (typ.)

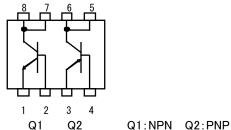
- Note 1: Please use devices on condition that the junction temperature is below 150°C. lcp= \pm 8A (@ t \leq 100 μ s)
- Note 2: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)
- Note 3: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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Figure 1. Circuit configuration (top view)

TOSHIBA



8902 ◆ _ Type

Lot No.

(Weekly code)

Figure 2. Marking (Note 4)

Note 4: ● on lower left on the marking indicates Pin 1.

Weekly code: (Three digits)



Week of manufacture

(01 for first week of year, continues up to 52 or 53)

Year of manufacture

(One low-order digits of calendar year)

Electrical Characteristics (Ta = 25°C)

PNP

| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|------------------|-----------------------|--|-----|------|-------|------|
| Collector cut-off current | | I _{CBO} | $V_{CB} = -30 \text{ V}, I_E = 0$ | _ | _ | -100 | nA |
| Emitter cut-off current | | I _{EBO} | $V_{EB} = -7 \text{ V}, I_{C} = 0$ | _ | _ | -100 | nA |
| Collector-emitter b | reakdown voltage | V (BR) CEO | $I_C = -10 \text{ mA}, I_B = 0$ | -30 | _ | _ | V |
| DC current gain | | h _{FE} (1) | $V_{CE} = -2 \text{ V}, I_{C} = -0.2 \text{ A}$ | 200 | _ | 500 | |
| | | h _{FE} (2) | $V_{CE} = -2 \text{ V}, I_{C} = -0.6 \text{ A}$ | 125 | _ | _ | |
| | | h _{FE} (3) | $V_{CE} = -2 \text{ V}, I_{C} = -2.0 \text{ A}$ | 40 | _ | _ | |
| Collector-emitter saturation voltage | | V _{CE} (sat) | $I_C = -0.6 \text{ A}, I_B = -20 \text{ mA}$ | _ | _ | -0.20 | V |
| Base-emitter saturation voltage | | V _{BE (sat)} | $I_C = -0.6 \text{ A}, I_B = -20 \text{ mA}$ | _ | _ | -1.10 | V |
| Collector output capacitance | | C _{ob} | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{MHz}$ | _ | 16.5 | _ | pF |
| Switching time | Rise time | t _r | See Figure 3 circuit diagram V _{CC} ≒-18 V, R _L = 30 Ω I _{B1} = I _{B2} = 20 mA | _ | 40 | _ | ns |
| | Storage time | t _{stg} | | _ | 280 | _ | |
| | Fall time | t _f | | _ | 40 | _ | |

NPN

| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|--------------|-----------------------|---|-----|------|------|------|
| Collector cut-off current | | I _{CBO} | $V_{CB} = 60 \text{ V}, I_{E} = 0$ | _ | _ | 100 | nA |
| Emitter cut-off current | | I _{EBO} | $V_{EB} = 7 \text{ V, } I_{C} = 0$ | _ | _ | 100 | nA |
| Collector-emitter breakdown voltage | | V (BR) CEO | $I_C = 10 \text{ mA}, I_B = 0$ | 30 | _ | _ | V |
| DC current gain | | h _{FE} (1) | V _{CE} = 2 V, I _C = 0.2 A | 200 | _ | 500 | |
| | | h _{FE} (2) | V _{CE} = 2 V, I _C = 0.6 A | 125 | _ | _ | |
| | | h _{FE} (3) | V _{CE} = 2 V, I _C = 2.0 A | 40 | _ | _ | |
| Collector-emitter saturation voltage | | V _{CE} (sat) | I _C = 0.6 A, I _B = 20 mA | _ | _ | 0.14 | V |
| Base-emitter saturation voltage | | V _{BE (sat)} | $I_C = 0.6 \text{ A}, I_B = 20 \text{ mA}$ | _ | _ | 1.10 | V |
| Collector output capacitance | | C _{ob} | $V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{MHz}$ | _ | 14 | _ | pF |
| Switching time | Rise time | t _r | See Figure 4 circuit diagram V _{CC} ≒18 V, R _L = 30 Ω I _{B1} = I _{B2} = 20 mA | _ | 45 | _ | ns |
| | Storage time | t _{stg} | | _ | 580 | _ | |
| | Fall time | t _f | | _ | 45 | _ | |

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Figure 3. Switching Time Test Circuit & Timing Chart

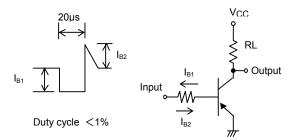
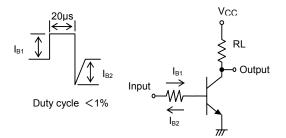
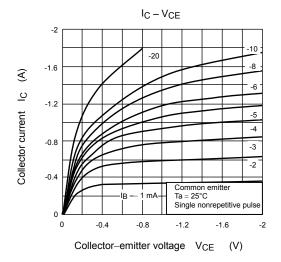


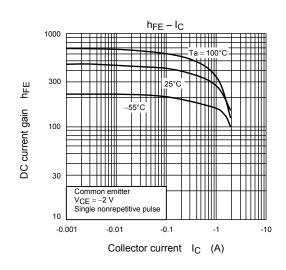
Figure 4. Switching Time Test Circuit & Timing Chart

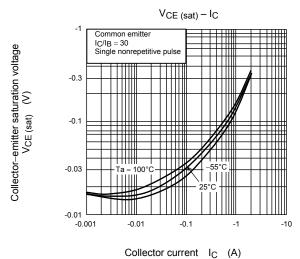


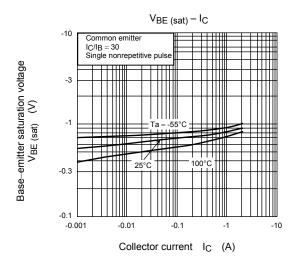
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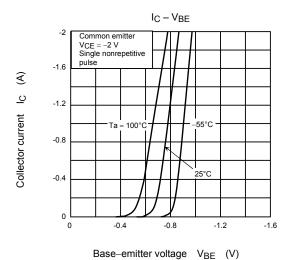
PNP

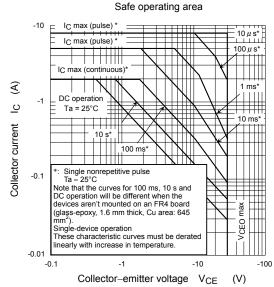






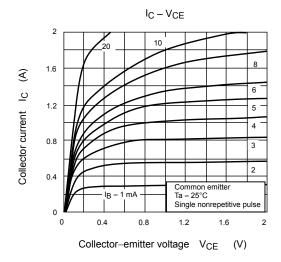


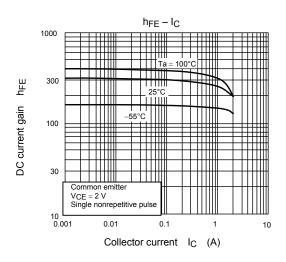


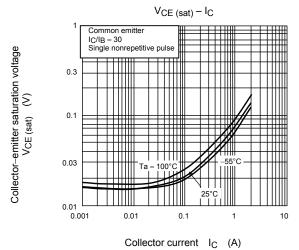


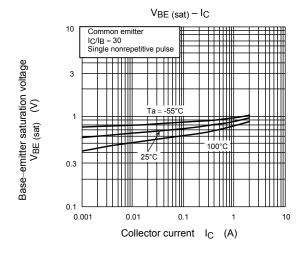
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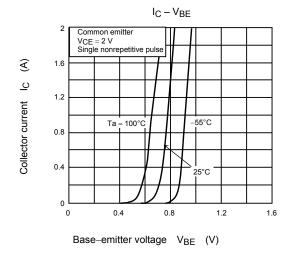
NPN

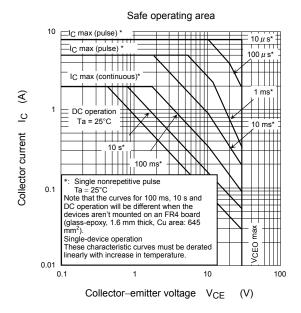




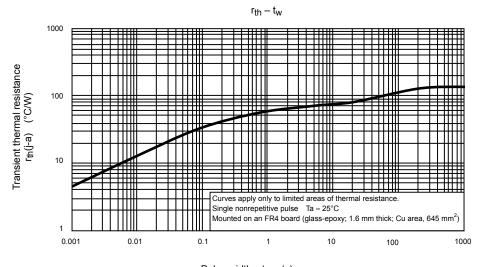






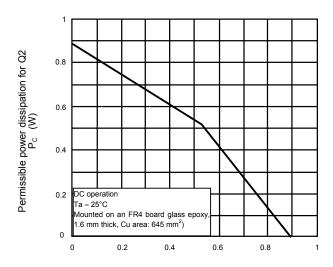


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Pulse width t_W (s)

Permissible Power Dissipation for Simultaneous Operation



Permissible power dissipation for Q1 $$P_{\mathbb{C}}$$ (W)

Collector power dissipation at the single-device operation is 0.89W. Collector power dissipation at the single-device value at dual operation is 0.52W.

Collector power dissipation at the dual operation is set to 1.04W.

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